





40V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

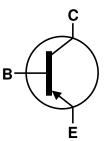
- $BV_{CEO} > -40V$
- I_C = -3A Max Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- $R_{CE(SAT)} = 58m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage (-200mV max @ 1A)
- hFF Characterized up to -5A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

Mechanical Data

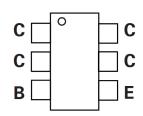
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (Approximate)







Device Symbol



Pin-Out Top

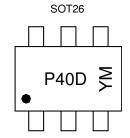
Ordering Information (Notes 4 & 5)

1					
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13P40DE6TA	AEC-Q101	P40D	7	8	3,000
ZXT13P40DE6QTA	Automotive	P40D	7	8	3.000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/. 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



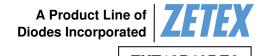
P40D = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	201	5	2016	2017	2018	2019	2020	2021	1 20	22	2023	2024	2025
Code	С		D	Е	F	G	Н	- 1	,	J	K	L	М
Monti	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		1	2	3	4	5	6	7	8	9	0	N	D





Absolute Maximum Ratings (@TA = +25 ℃, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7.5	V
Base Current	I _B	-500	mA
Continuous Collector Current	Ic	-3	Α
Peak Pulse Collector Current	I _{CM}	-10	Α

Thermal Characteristics (@TA = +25 °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	D	1.1 8.8	W mW/℃	
Linear Derating Factor	(Note 7)	P _D	1.7 13.6		
Thermal Resistance, Junction to Ambient	(Note 6)	Б	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	73		
Thermal Resistance, Junction to Lead (Note 8)		$R_{ heta JL}$	18.6		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	℃	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{6.} For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

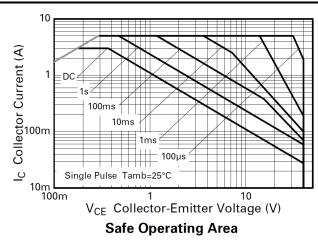
^{7.} Same as Note 6, except the device is measured at $t \leq 5 \text{secs.}$

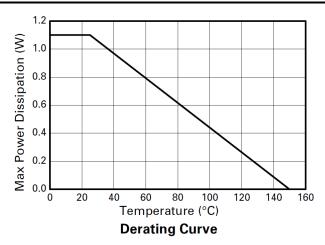
^{8.} Thermal resistance from junction to solder-point (at the end of the collector leads).

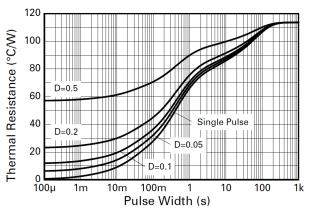
^{9.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information

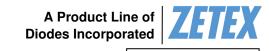






Transient Thermal Impedance





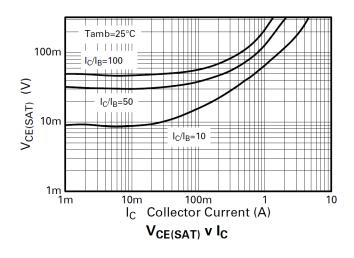
Electrical Characteristics (@TA = +25 °C, unless otherwise specified.)

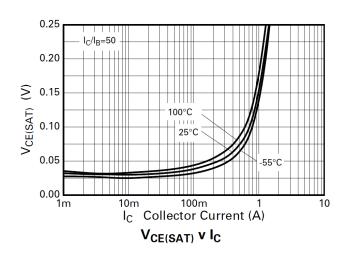
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage		-50	-80		V	$I_C = -100\mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-40	-70	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7.5	-8.5	_	V	$I_E = -100 \mu A$
Collector-Base Cut-Off Current	I _{CBO}	_	_	-100	nA	V _{CB} = -40V
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	V _{EB} = -6V
Collector-Emitter Cut-Off Current	Ices	_	_	-100	nA	V _{CES} = -40V
ON CHARACTERISTICS (Note 10)	•		•		•	
		300	500		_	$I_C = -10mA$, $V_{CE} = -2V$
DC Current Gain	h	300	450	900	_	$I_C = -1A$, $V_{CE} = -2V$
DC Guirent Gam	h _{FE}	100	250		_	$I_C = -3A$, $V_{CE} = -2V$
		15	50		_	$I_C = -5A$, $V_{CE} = -2V$
	V _{CE(sat)}	_	-16	-25	mV	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$
Collector-Emitter Saturation Voltage		_	-110	-200		$I_C = -1A$, $I_B = -20mA$
Collector-Emitter Saturation Voltage		_	-145	-190		$I_C = -2A$, $I_B = -100mA$
		_	-175	-240		$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	_	-1.1	V	I _C = -3A, I _B = -300mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	_	-0.9	V	I _C = -3A, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS			•		•	
Current Gain-Bandwidth Product	f _T	_	115	_	MHz	V _{CE} = -10V, I _C = -50mA, f = 50MHz
Output Capacitance	C _{obo}	_	42	_	pF	V _{CB} = -10V, f = 1MHz
Turn-On Time	t _(on)	_	185	_	ns	V _{CC} = -10V, I _C = -1A
Turn-Off Time	t _(off)		400		ns	$I_{B1} = I_{B2} = -20mA$

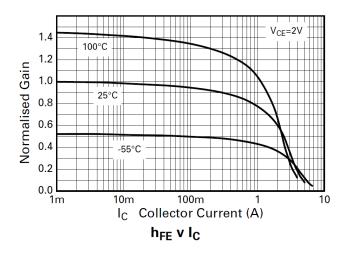
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

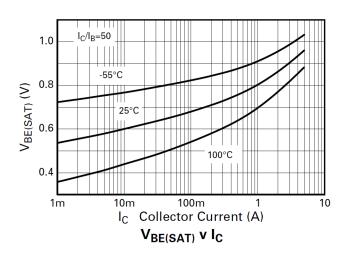


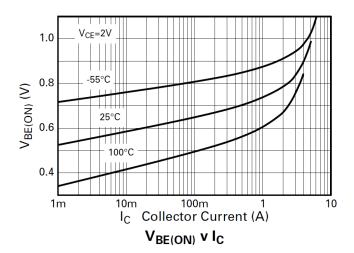
Typical Electrical Characteristics (@T_A = +25 ℃, unless otherwise specified.)







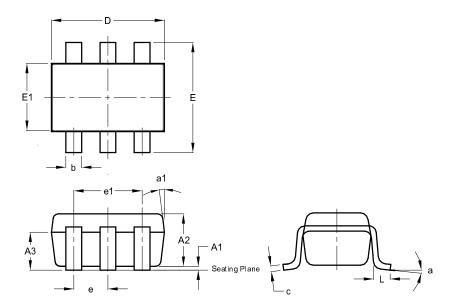






Package Outline Dimensions

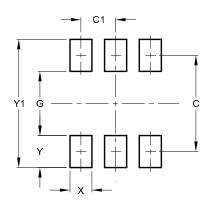
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26								
Dim	Min	Max	Тур					
A1	0.013	0.10	0.05					
A2	1.00	1.30	1.10					
A 3	0.70	0.80	0.75					
b	0.35	0.50	0.38					
C	0.10	0.20	0.15					
D	2.90	3.10	3.00					
е	-	-	0.95					
e1	-	-	1.90					
Е	2.70	3.00	2.80					
E1	1.50	1.70	1.60					
L	0.35	0.55	0.40					
а	-	1	8°					
a1	-	-	7°					
All Dimensions in mm								

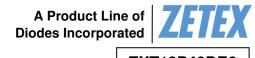
Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
X	0.55
Υ	0.80
Y1	3.20





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